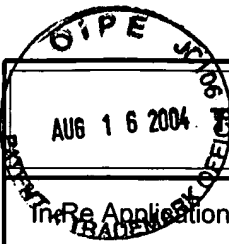


IFW



<b>TRANSMITTAL OF FORMAL DRAWINGS</b>	Docket No. <b>FIS920030367US1 (17139)</b>
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Inventor's Name: **Xiangdong Chen**

Application No. <b>10/708,381</b>	Filing Date <b>February 27, 2004</b>	Confirmation No. <b>2380</b>	Examiner <b>Unknown</b>	Customer No. <b>23389</b>	Group Art Unit <b>2818</b>
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Invention: **GATE CONTROLLED FLOATING WELL VERTICAL MOSFET**

Address to:  
**Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450**

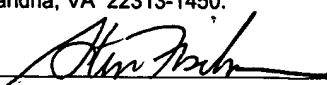
Transmitted herewith are:

**9** sheets of formal drawing(s) for this application.

☒ Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

  
Signature  
**Steven Fischman**  
**Registration No. 34,594**  
  
**SCULLY, SCOTT, MURPHY & PRESSER**  
**400 Garden City Plaza**  
**Garden City, New York 11530**  
**(516) 742-4343**

Dated: **August 13, 2004**

I certify that this document and attached formal drawings are being deposited on <b>August 13, 2004</b> with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.
 Signature of Person Mailing Correspondence
<b>Steven Fischman</b> Typed or Printed Name of Person Mailing Correspondence